



## Data Sheet

---

Customer: \_\_\_\_\_

Part No: \_\_\_\_\_

CL-5019EGW1C-001-CC

Sample No: \_\_\_\_\_

Description: \_\_\_\_\_

5Ø Lamp R+YG Color

Item No: \_\_\_\_\_

Customer			
Check	Inspection	Approval	Date

**Features**

- Low Power Consumption
- High Efficiency
- Round Type
- T1 ( 5mm ) Diameter
- With Flange
- Solder Leads Without Stand-off
- Compliant With RoHS

**Descriptions**

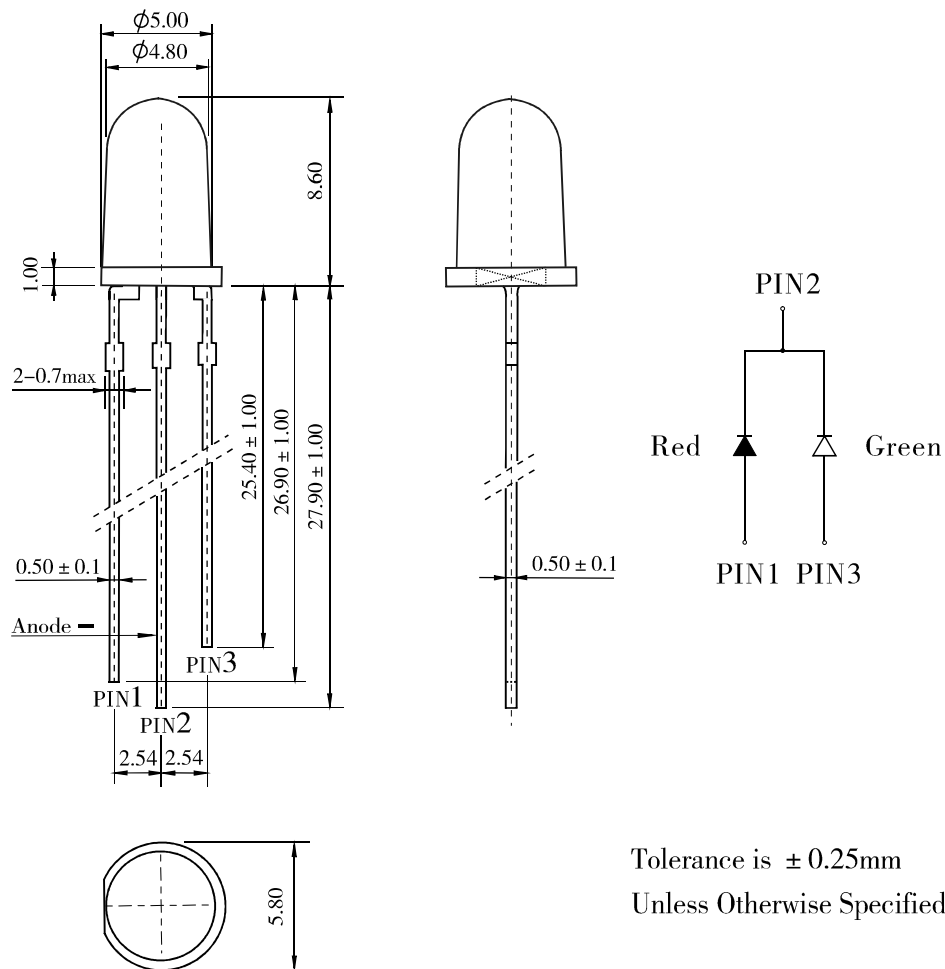
- Chip Material: AlGaAs/GaAs、 GaP/GaP
- Emitting Color: Red、 Green
- Lens Color: White Diffused

**ATTENTION**



OBSERVE PRECAUTIONS  
FOR HANDLING  
ELECTROSTATIC  
SENSITIVE DEVICES

**Outline Drawing**



Tolerance is  $\pm 0.25\text{mm}$   
Unless Otherwise Specified.

**Electrical Optical Characteristics ( Ta=25°C )**

Parameter	Symbol	Red			Unit	Test Condition
		Min	Typ	Max		
Forward Voltage	$V_F$	---	2.00	2.40	V	IF=20mA
Luminous Intensity	$I_v$	19.0	26.6	---	mcd	IF=20mA
Peak Wavelength	$\lambda_P$	---	632	---	nm	IF=20mA
Dominant Wavelength	$\lambda_d$	---	624	---	nm	IF=20mA
Spectral Line half-width	$\Delta\lambda$	---	20	---	nm	IF=20mA
Reverse Leakage Current	$I_R$	---	---	50	$\mu A$	VR=5V
Viewing Angle	$2\theta_{1/2}$	---	60	---	Deg	IF=20mA

**Absolute Maximum Parameters ( Ta=25°C )**

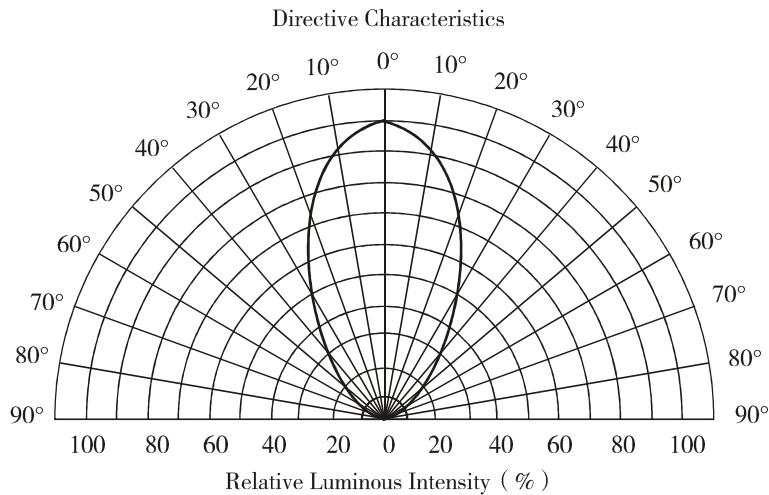
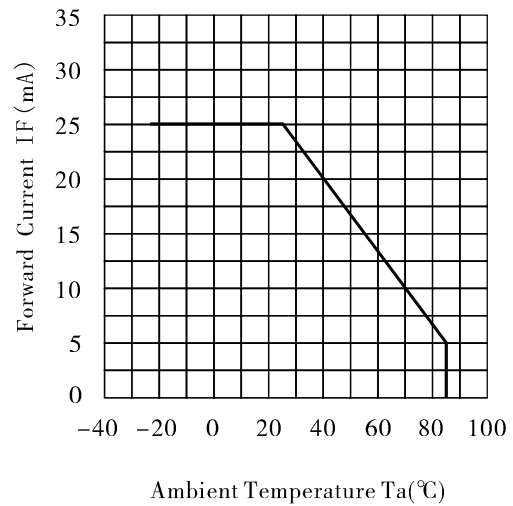
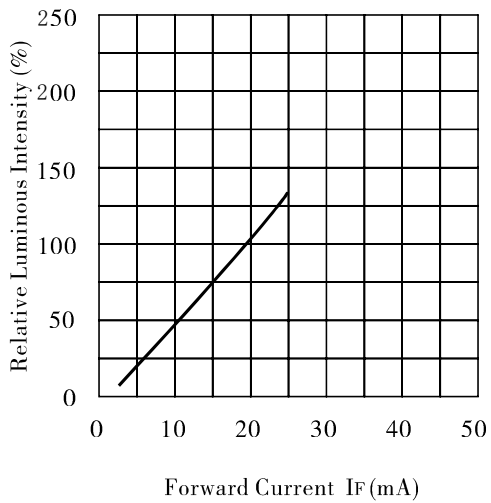
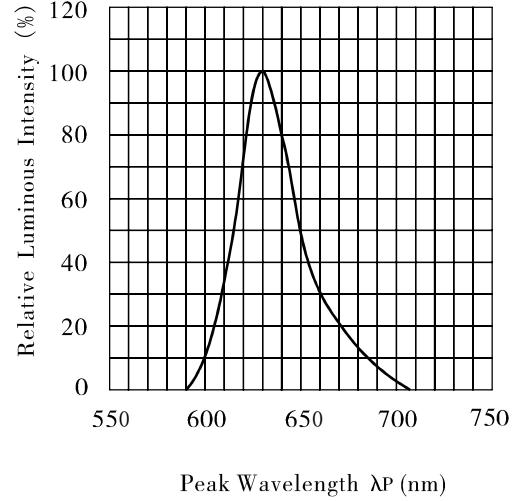
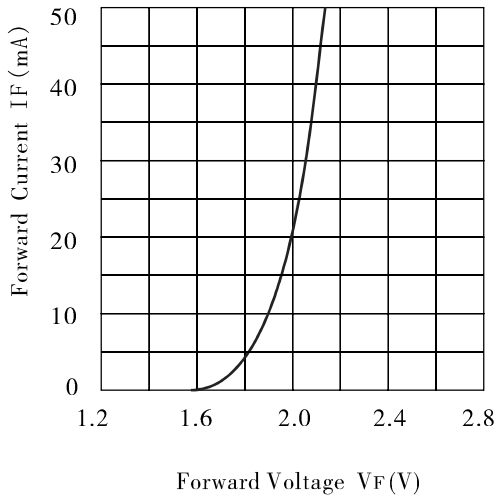
Parameter	Symbol	Condition	Rating	Unit
Power Dissipation	$P_D$	---	60	mW
Reverse Voltage	$V_R$	---	5	V
Forward Average Current	$I_F$	---	25	mA
Temperature coefficient	I/C	---	0.33	mA/ °C
Pulse Current	IFP	Duty=1/10,1kHz	100	mA
Operating Temperature Range	$T_{opr}$	---	-25 ~ +85	°C
Storage Temperature Range	$T_{stg}$	---	-30 ~ +100	°C
Soldering Condition	$T_{sd}$	---	260°C/5sec	°C

**NOTE:**

Luminous Intensity Measurement allowance is  $\pm 10\%$ .

$2\theta_{1/2}$  is the off-axis angle at which the luminous intensity is half the axial luminous intensity.

The dominant wavelength is derived from the CIE chromaticity diagram and represents the single wavelength which defines the color of the device.

**Typical Electro-Optical Characteristic Curves ( Ta=25°C )**


**Electrical Optical Characteristics ( Ta=25°C )**

Parameter	Symbol	Green			Unit	Test Condition
		Min	Typ	Max		
Forward Voltage	$V_F$	---	2.00	2.40	V	IF=20mA
Luminous Intensity	$I_v$	26.6	37.2	---	mcd	IF=20mA
Peak Wavelength	$\lambda_P$	---	568	---	nm	IF=20mA
Dominant Wavelength	$\lambda_d$	---	572	---	nm	IF=20mA
Spectral Line half-width	$\Delta\lambda$	---	30	---	nm	IF=20mA
Reverse Leakage Current	$I_R$	---	---	50	$\mu A$	VR=5V
Viewing Angle	$2\theta_{1/2}$	---	60	---	Deg	IF=20mA

**Absolute Maximum Parameters ( Ta=25°C )**

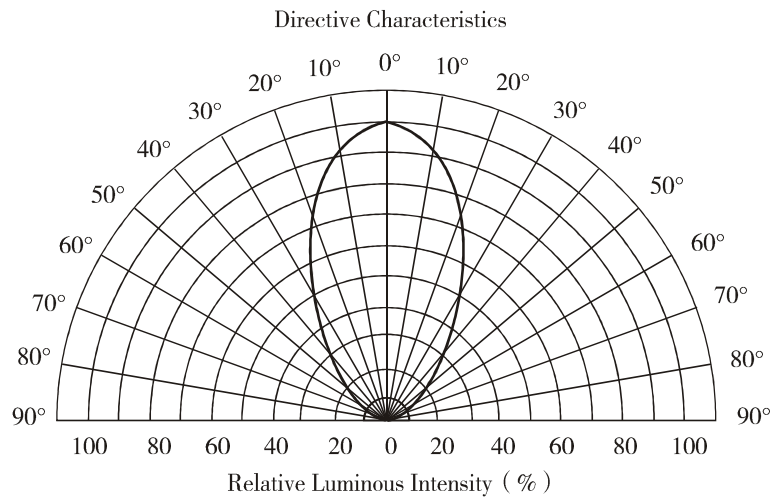
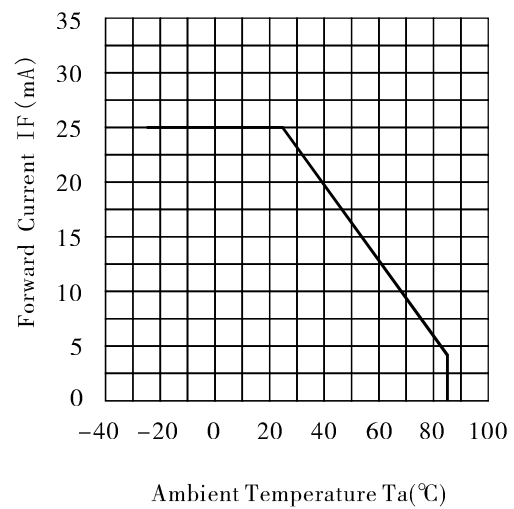
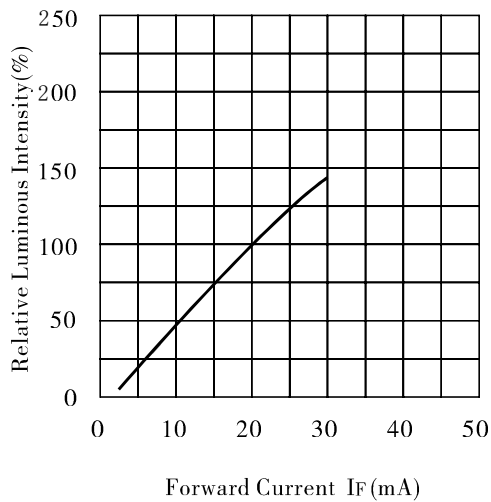
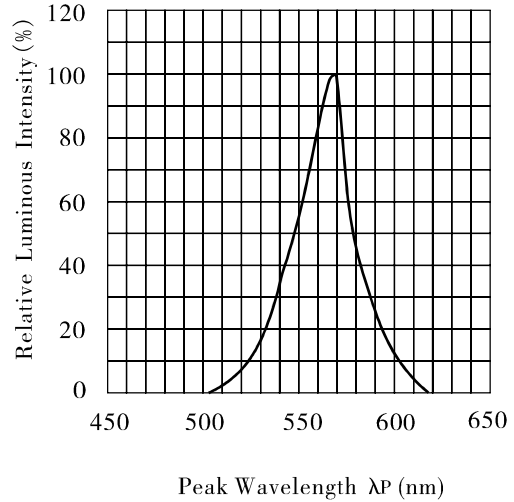
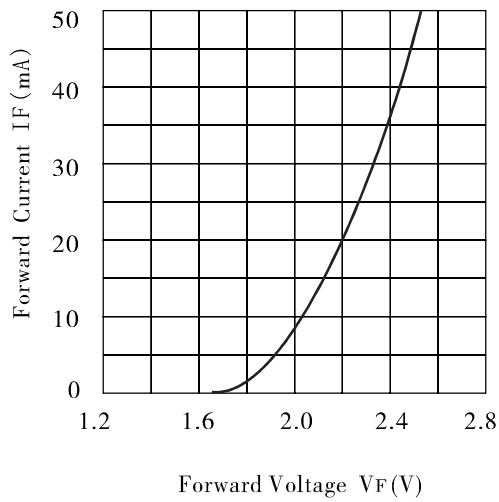
Parameter	Symbol	Condition	Rating	Unit
Power Dissipation	$P_D$	---	60	mW
Reverse Voltage	$V_R$	---	5	V
Forward Average Current	$I_F$	---	30	mA
Temperature coefficient	I/C	---	0.33	mA/ °C
Pulse Current	IFP	Duty=1/10,1kHz	100	mA
Operating Temperature Range	$T_{opr}$	---	-25 ~ +85	°C
Storage Temperature Range	$T_{stg}$	---	-30 ~ +100	°C
Soldering Condition	$T_{sd}$	---	260°C/5sec	°C

**NOTE:**

Luminous Intensity Measurement allowance is  $\pm 10\%$ .

$2\theta_{1/2}$  is the off-axis angle at which the luminous intensity is half the axial luminous intensity.

The dominant wavelength is derived from the CIE chromaticity diagram and represents the single wavelength which defines the color of the device.

Typical Electro-Optical Characteristic Curves (  $T_a=25^\circ\text{C}$  )


## BIN Sub-Scale

Unit: @20mA		Luminous Intensity		Dominant Wavelength	
BIN Code	Color	Min	Max	Min	Max
F	Red	19.0	26.6	618	626
G		26.6	37.2	618	626
H		37.2	52.0	618	626
G	Green	26.6	37.2	568	574
H		37.2	52.0	568	574
J		52.0	72.8	568	574

Note: Tolerance of each bin limit is  $\pm 15\%$

## Reliability Test Conditions

Test Item	Test Condition	Result	Judgment Criteria
Consecutive operating life test	IF=20mA, T=25℃, t=168h	0/100	Forward Voltage $V_F(V) = \text{Upper Limit} \times 1.2$ Reverse Leakage Current $I_R(\mu A) = \text{Upper Limit} \times 2.0$ Luminous Intensity IV (mcd) = Lower Limit $\times 0.7$
High temperature storage life test	T=100℃, t=168h	0/100	
Low temperature storage life test	T=25℃, t=168h	0/100	
High temperature humidity storage life test	T=85 ± 2℃, RH=85% ± 3, t=168h	0/100	
Temperature cycle test	-25℃~25℃~100℃ 30min 5min 30min 10cycles	0/100	
Thermal shock test	100℃ 0℃ 5min 5min 20cycles	0/100	
Soldering heat test	T=260 ± 5℃, t=10s ± 1s	0/100	
Solderability test	T=235 ± 5℃, t=5s ± 0.5s	0/100	Steeped Part ≥ 95%
Fall test	h=100cm, 50times	0/100	Surface Appearance Photoelectric Properties Intact
Terminal strength test	W=9.8N, t=30 ± 5s	0/100	
Lead bending test	W=4.9N, 2times	0/100	